TOSHIBA TC7WH14FU/FK

TENTATIVE

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC7WH14FU, TC7WH14FK

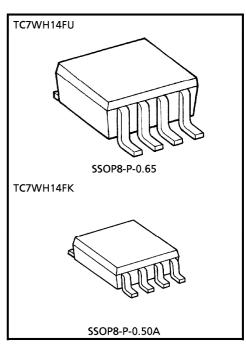
(UNDER DEVELOPMENT)

TRIPLE SCHMITT INVERTER

The TC7WH14 is an advanced high speed CMOS SCHMITT INVERTER fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. Pin configuration and function are the same as the TC7SH14 but the inputs have hysteresis and with its schmitt trigger function, the TC7SH14 can be used as a line receivers which will receive slow input signals. An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES

- t_{pd} = 5.5ns (Typ.) at V_{CC} = 5V High Speed
- Low Power Dissipation $I_{CC} = 2\mu A$ (Max.) at
 - High Noise Immunity $\cdots V_{NIH} = V_{NIL} = 28\% V_{CC}$
- (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays $\cdots t_{pLH} = t_{pHL}$
- Wide Operating Voltage Range ··· V_{CC} (opr) = 2~5.5V

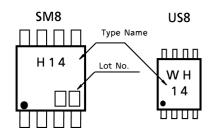


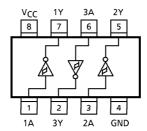
Weight

SSOP8-P-0.65 : 0.02g (Typ.) SSOP8-P-0.50A : 0.01g (Typ.)

MARKING

PIN ASSIGNMENT (TOP VIEW)





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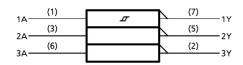
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MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Supply Voltage Range	Vcc	-0.5~7.0	V	
DC Input Voltage	VIN	-0.5~7.0	V	
DC Output Voltage	Vout	-0.5~V _{CC} +0.5	٧	
Input Diode Current	IK	- 20	mA	
Output Diode Current	lok	± 20	mA	
DC Output Current	IOUT	± 25	mA	
DC V _{CC} /Ground Current	lcc	± 50	mA	
Power Dissipation	D-	300 (SM8)	mW	
Power Dissipation	PD	200 (US8)	IIIVV	
Storage Temperature	T _{stg}	-65∼150	°C	
Lead Temperature (10 s)	TL	260	°C	

LOGIC DIAGRAM



TRUTH TABLE

Α	Υ
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Н	L

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Supply Voltage	Vcc	2.0~5.5	V	
Input Voltage	VIN	0~5.5	٧	
Output Voltage	Vout	0~V _{CC}	V	
Operating Temperature	T _{opr}	- 40∼85	°C	
Input Rise and Fall Time	dt/dv	$0 \sim 100 \text{ (V}_{CC} = 3.3 \pm 0.3 \text{V)}$	ns / V	
Input Rise and Fan Time	at/av	$0\sim20 (V_{CC} = 5 \pm 0.5V)$		

DC ELECTRICAL CHARACTERISTICS

CHADACTERISTIC	SYMBOL	TEST CONDITION		V _С С (V)	Ta = 25°C			Ta = −40~85°C		UNIT
CHARACTERISTIC	STIVIBUL	1531 C	TEST CONDITION		MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
Positive				3.0	_	_	2.20	_	2.20	
Threshold	VP			4.5	_	_	3.15	_	3.15	V
Voltage				5.5	_	_	3.85	_	3.85	
Negative				3.0	0.90	_	_	0.90	_	
Threshold	٧N			4.5	1.35	_	_	1.35	_	V
Voltage				6.0	1.65	_	_	1.65	_	
Hysteresis				3.0	0.30	_	1.20	0.30	1.20	
Voltage	VH			4.5	0.40	_	1.40	0.40	1.40	V
Voltage				5.5	0.50	_	1.60	0.50	1.60	
	V _{ОН}	V _{IN} = V _{IL}	I _{OH} = -50μA	2.0	1.9	2.0	_	1.9	_	v
High-Level				3.0	2.9	3.0	_	2.9	_	
Output Voltage				4.5	4.4	4.5	_	4.4	_	
Output Voltage			$I_{OH} = -4mA$	3.0	2.58	_		2.48	_	
			$I_{OH} = -8mA$	4.5	3.94	_	_	3.80	_	
		V _{IN} = V _{IH}	I _{OL} = 50μA	2.0	_	0.0	0.1	_	0.1	V
Low-Level				3.0		0.0	0.1	_	0.1	
Output Voltage	VOL			4.5	_	0.0	0.1	_	0.1	
Output Voltage			$I_{OL} = 4mA$	3.0	_	_	0.36	_	0.44	
			IOL = 8mA	4.5	_	_	0.36	_	0.44	
Input Leakage Current	I _{IN}	V _{IN} = 5.5V or GND		0~ 5.5	_	_	± 0.1	_	± 1.0	μ A
Quiescent Supply Current	lcc	V _{IN} = V _{CC} o	or GND	5.5	_	_	2.0	_	20.0	μΑ

AC	ELECTRICAL	CHARACTERISTICS	(Input $t_r = t_f = 3ns$)
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CHARACTERISTIC	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = -40~85°C		UNIT	
CHARACTERISTIC STIVI			V _{CC} (V)	C _L (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
		I	3.3 ± 0.3	15	_	8.3	12.8	1.0	15.0	
	^t pLH ^t pHL		3.3 ± 0.3	50	_	10.8	16.3	1.0	18.5	
			5.0 ± 0.5	15	_	5.5	8.6	1.0	10.0	ns
				50		7.0	10.6	1.0	12.0	
Input Capacitance	C _{IN}		_			4	10	_	10	рF
Power Dissipation	Coo	(Note 1)	Note 1)			21				рF
Capacitance	C _{PD}	(Note 1)				21	_	_	_	ы

(Note 1): CpD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

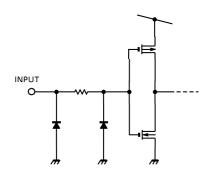
Average operating current can be obtained by the equation:

ICC (opr) = CpD · VCC · fIN + ICC

NOISE CHARACTERISTICS (Ta = 25°C, Input $t_r = t_f = 3ns$)

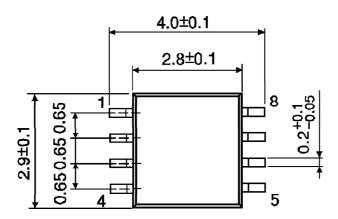
CHARACTERISTIC	SYMBOL	TEST CONDITION	V _{CC} (V)	TYP.	LIMIT	UNIT
Quiet Output Maximum Dynamic V _{OL}	V _{OLP}	C _L = 50pF	5.0	0.3	0.8	V
Quiet Output Minimum Dynamic V _{OL}	V _{OLV}	C _L = 50pF	5.0	-0.3	-0.8	V
Minimum High Level Dynamic Input Voltage	V _{IHD}	C _L = 50pF	5.0	_	3.5	V
Maximum Low Level Dynamic Input Voltage	V _{ILD}	C _L = 50pF	5.0	_	1.5	V

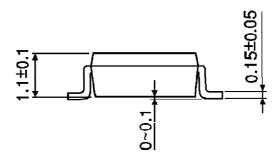
INPUT EQUIVALENT CIRCUIT



OUTLINE DRAWING SSOP8-P-0.65

Unit: mm

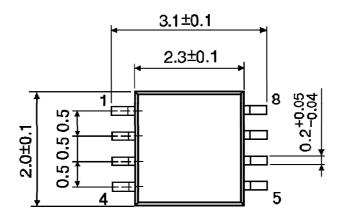


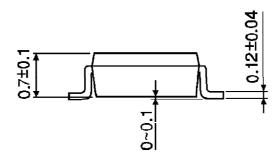


Weight: 0.02g (Typ.)

OUTLINE DRAWING SSOP8-P-0.50A

Unit: mm





Weight: 0.01g (Typ.)